

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

### IRFB4310ZPBF

#### • FEATURES

- With TO-220 packaging
- High speed switching
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

- Power supply
- DC-DC converters
- Motor control
- Switching applications

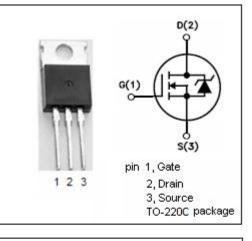
SYMBOL	PARAMETER		VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage		100	V	
V <sub>GSS</sub>	Gate-Source Voltage		±20	V	
ID	Drain Current-Continuous Tc=2 Tc=1	25℃ 00℃	127 90	А	
I <sub>DM</sub>	Drain Current-Single Pulsed		560	А	
PD	Total Dissipation		250	W	
Tj	Operating Junction Temperature		-55~175	°C	
T <sub>stg</sub>	Storage Temperature		-55~175	°C	

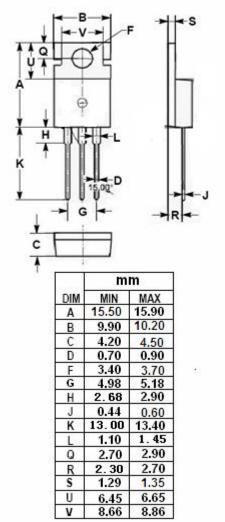
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance		°C <b>/W</b>	
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C/W	

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#### isc website: www.iscsemi.cn



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#### **ELECTRICAL CHARACTERISTICS**

#### $T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	100			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =±20V; I <sub>D</sub> =0.15mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =75A		4.8	6.0	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0V;Tj=25℃ V <sub>DS</sub> = 80V; V <sub>GS</sub> = 0V;Tj=125℃			20 250	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =75A, V <sub>GS</sub> = 0 V			1.3	V

#### **NOTICE:**

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